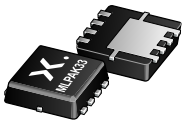


PXP1500-100QS

100 V, P-channel Trench MOSFET

20 November 2021 **Product data sheet**

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in an MLPAK33 (SOT8002-2) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Trench MOSFET technology
- MLPAK33 package (3.3 x 3.3 mm footprint)
- Low thermal resistance
- Low 0.8 mm profile

3. Applications

- Active clamp circuits

4. Quick reference data

Table 1. Quick reference data

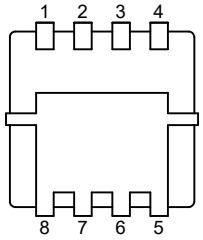
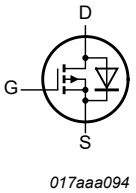
Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{DS}	drain-source voltage	T_j = 25 °C		-	-	-100	V
V_{GS}	gate-source voltage			-20	-	20	V
I_D	drain current	V_{GS} = -10 V; T_{amb} = 25 °C	[1]	-	-	-0.7	A
Static characteristics							
R_{DSon}	drain-source on-state resistance	V_{GS} = -10 V; I_D = -0.7 A; T_j = 25 °C		-	930	1500	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm^2.

nexperia

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	 MLPAK33 (SOT8002-2)	 017aaa094
2	S	source		
3	S	source		
4	G	gate		
5	D	drain		
6	D	drain		
7	D	drain		
8	D	drain		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PXP1500-100QS	MLPAK33	plastic thermal enhanced surface mounted package; mini leads; 8 terminals; pitch 0.65 mm; 3.3 x 3.3 x 0.8 mm body	SOT8002-2

7. Marking

Table 4. Marking codes

Type number	Marking code
PXP1500-100QS	9AM

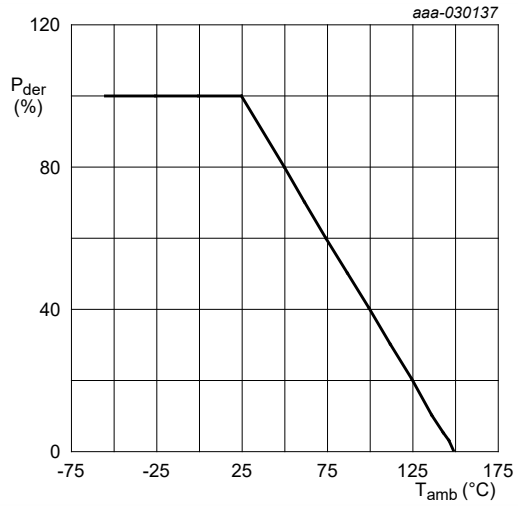
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

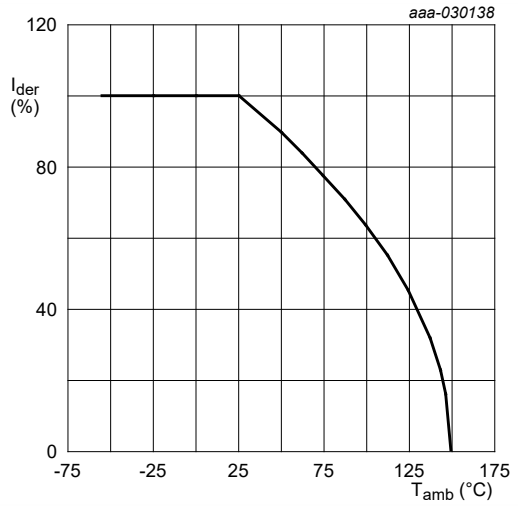
Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage	T_j = 25 °C		-	-100	V
V_{GS}	gate-source voltage			-20	20	V
I_D	drain current	V_{GS} = -10 V; T_{amb} = 25 °C	[1]	-	-0.7	A
		V_{GS} = -10 V; T_{amb} = 100 °C	[1]	-	-0.4	A
		V_{GS} = -10 V; T_{sp} = 25 °C		-	-1.4	A
I_{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \leq$ 10 µs		-	-3	A
P_{tot}	total power dissipation	T_{amb} = 25 °C	[1]	-	1.4	W
		T_{sp} = 25 °C		-	6.1	W
T_j	junction temperature			-55	150	°C
T_{amb}	ambient temperature			-55	150	°C
T_{stg}	storage temperature			-65	150	°C
Source-drain diode						
I_S	source current	T_{amb} = 25 °C	[1]	-	-0.66	A
Avalanche ruggedness						
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$T_{j(init)}$ = 25 °C; I_D = -0.6 A; DUT in avalanche (unclamped)		-	7	mJ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm^2.



$$P_{der} = \frac{P_{tot}}{P_{tot\,(25\,°C)}} \times 100\,\%$$

Fig. 1. Normalized total power dissipation as a function of ambient temperature



$$I_{der} = \frac{I_D}{I_{D\,(25\,°C)}} \times 100\,\%$$

Fig. 2. Normalized continuous drain current as a function of ambient temperature

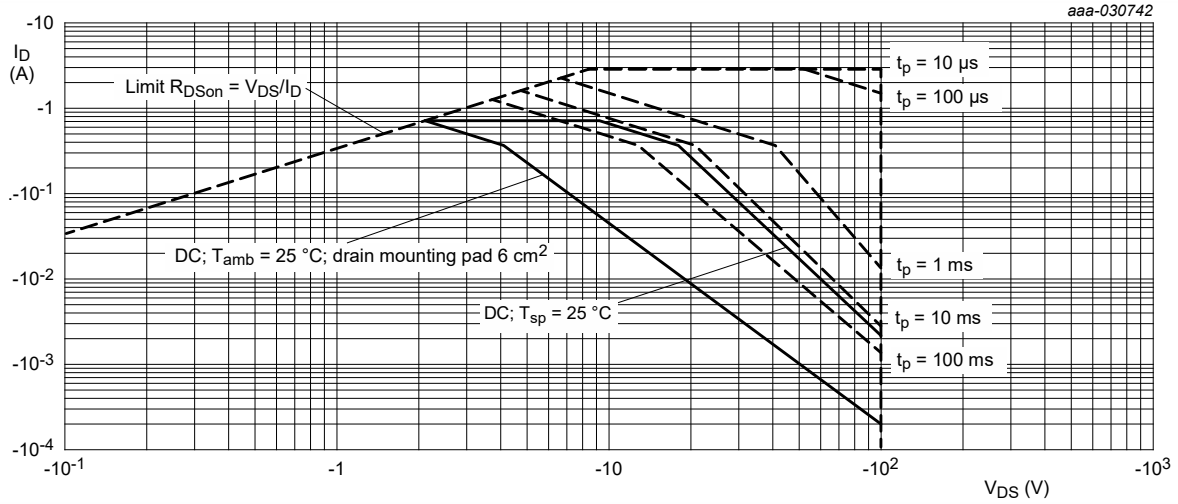


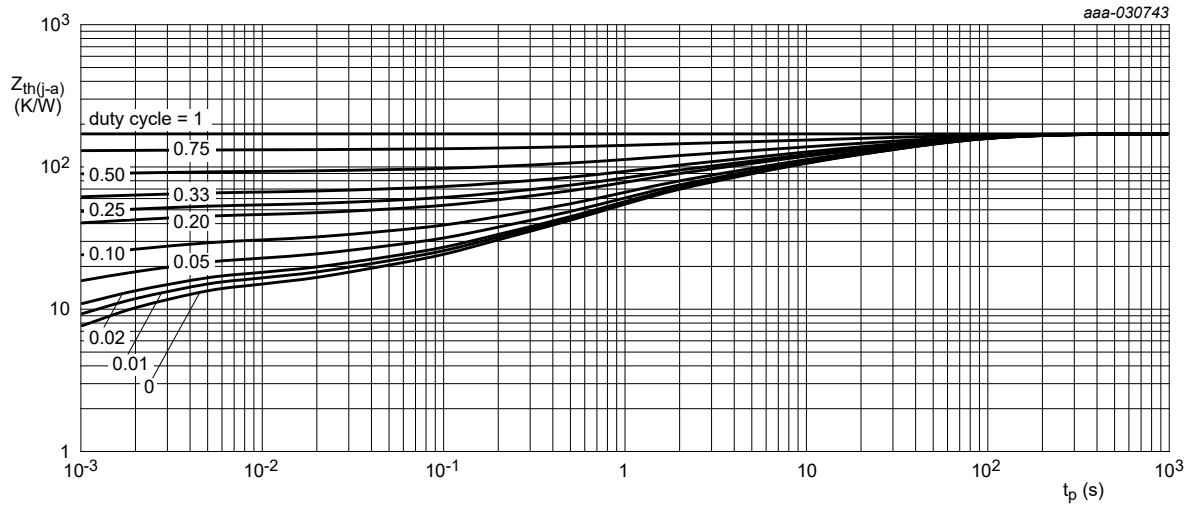
Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

9. Thermal characteristics

Table 6. Thermal characteristics

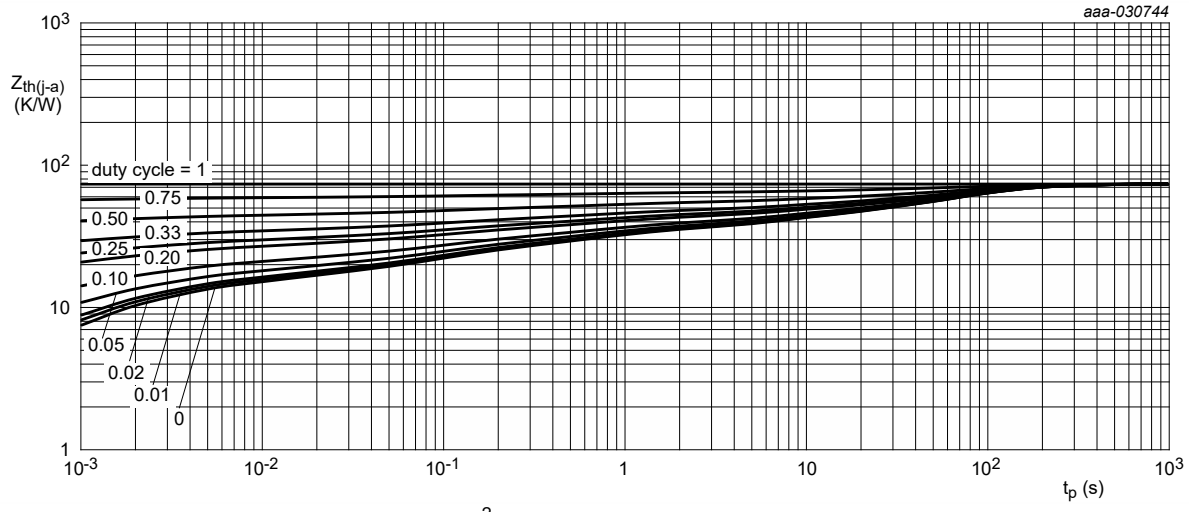
Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	170	205	K/W
			[2]	-	75	90	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	17.2	20.5	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm^2.



FR4 PCB, standard footprint

Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



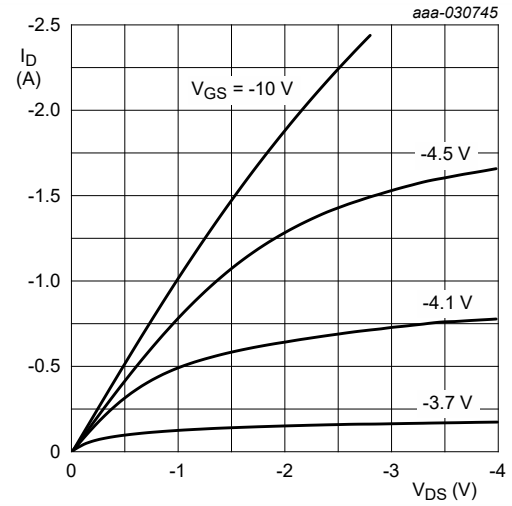
FR4 PCB, mounting pad for drain 6 cm^2

Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

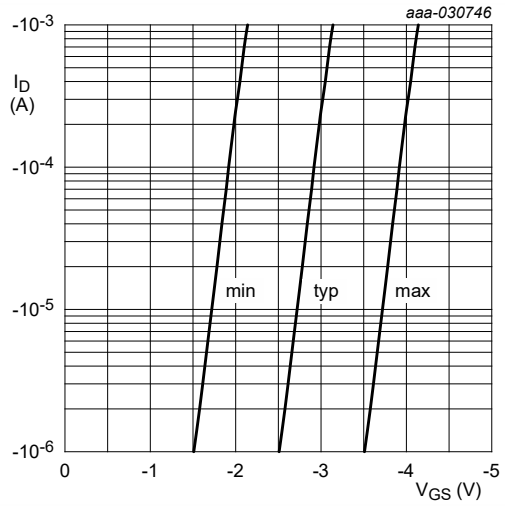
Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Static characteristics							
$V_{(BR)DSS}$	drain-source breakdown voltage	I_D = -250 µA; V_{GS} = 0 V; T_j = 25 °C		-100	-	-	V
V_{GSth}	gate-source threshold voltage	I_D = -250 µA; V_{DS} = V_{GS}; T_j = 25 °C		-2	-3	-4	V
I_{DSS}	drain leakage current	V_{GS} = 0 V; V_{DS} = -100 V; T_j = 25 °C		-	-	-1	µA
I_{GSS}	gate leakage current	V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C		-	-	-100	nA
		V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C		-	-	100	nA
R_{DSon}	drain-source on-state resistance	V_{GS} = -10 V; I_D = -0.7 A; T_j = 25 °C		-	930	1500	mΩ
		V_{GS} = -10 V; I_D = -0.7 A; T_j = 150 °C		-	2000	3165	mΩ
		V_{GS} = -6 V; I_D = -0.6 A; T_j = 25 °C		-	1000	1700	mΩ
g_{fs}	forward transconductance	V_{DS} = -5 V; I_D = -0.7 A; T_j = 25 °C		-	1.6	-	S
R_G	gate resistance	f = 1 MHz		-	26	-	Ω
Dynamic characteristics							
$Q_{G(tot)}$	total gate charge	V_{DS} = -50 V; I_D = -0.6 A; V_{GS} = -10 V; T_j = 25 °C		-	3.1	4.5	nC
		V_{DS} = -50 V; I_D = -0.6 A; V_{GS} = -6 V; T_j = 25 °C		-	2.1	3.1	nC
Q_{GS}	gate-source charge			-	0.6	-	nC
Q_{GD}	gate-drain charge			-	0.9	-	nC
C_{iss}	input capacitance	V_{DS} = -50 V; f = 1 MHz; V_{GS} = 0 V; T_j = 25 °C		-	159	-	pF
C_{oss}	output capacitance			-	8	-	pF
C_{rss}	reverse transfer capacitance			-	4.5	-	pF
$t_{d(on)}$	turn-on delay time	V_{DS} = -50 V; I_D = -0.6 A; V_{GS} = -6 V; $R_{G(ext)}$ = 5 Ω; T_j = 25 °C		-	5	-	ns
t_r	rise time			-	17	-	ns
$t_{d(off)}$	turn-off delay time			-	5	-	ns
t_f	fall time			-	12	-	ns
Source-drain diode							
V_{SD}	source-drain voltage	I_S = -0.7 A; V_{GS} = 0 V; T_j = 25 °C		-	-0.8	-1.2	V
t_{rr}	reverse recovery time	I_S = -0.6 A; dI_S/dt = -100 A/µs; V_{GS} = -6 V; V_{DS} = -40 V; T_j = 25 °C		-	24	-	ns
Q_r	recovered charge			-	20	-	nC



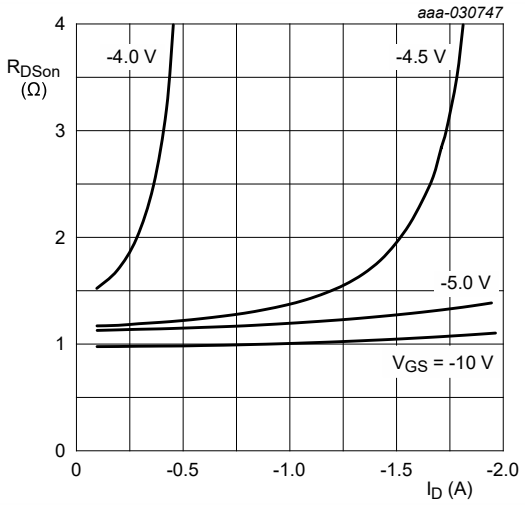
T_j = 25 °C

Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values



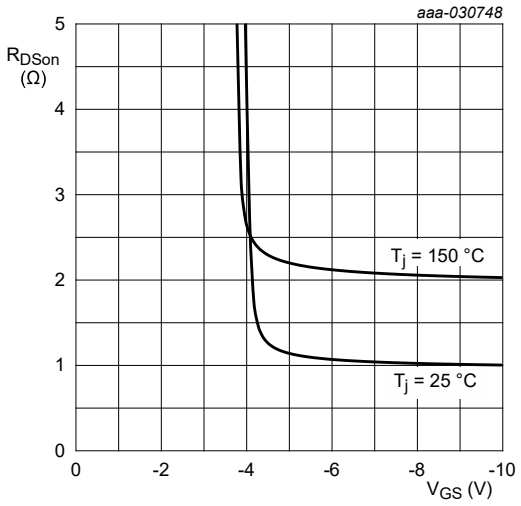
V_{DS} = -5 V; T_j = 25 °C

Fig. 7. Sub-threshold drain current as a function of gate-source voltage



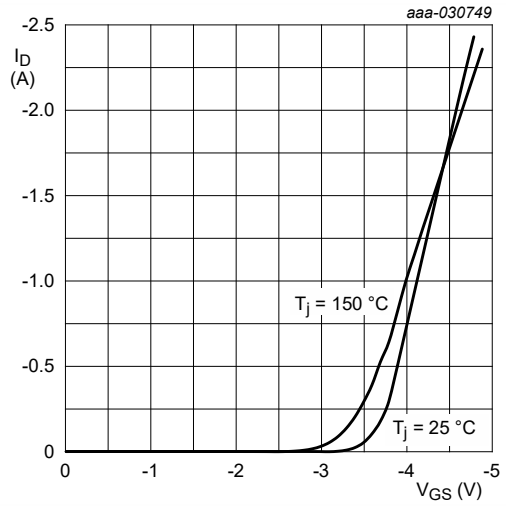
T_j = 25 °C

Fig. 8. Drain-source on-state resistance as a function of drain current; typical values



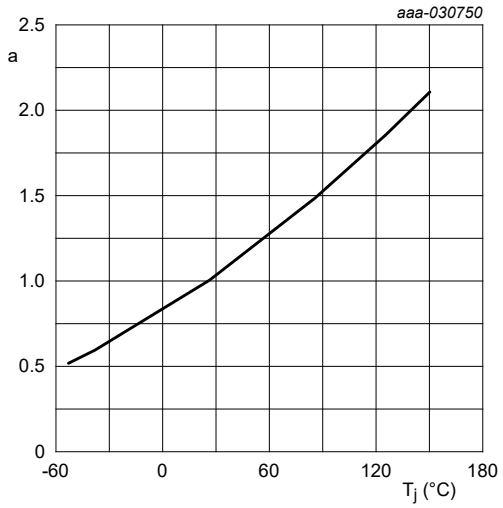
I_D = -0.6 A

Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values



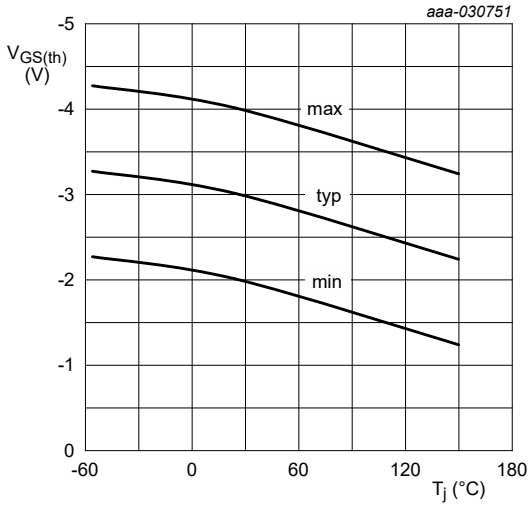
V_{DS} = -10 V

Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values



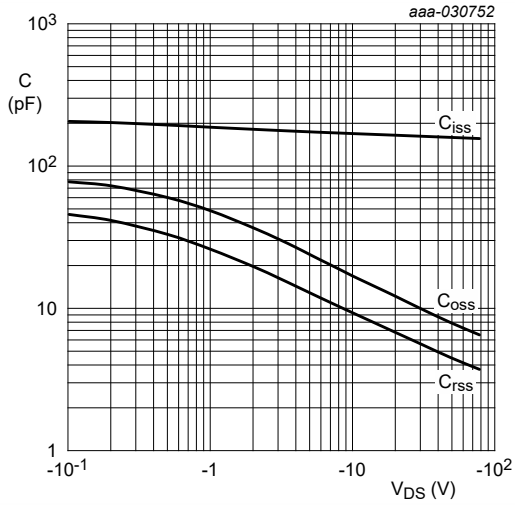
$$a = \frac{R_{DSon}}{R_{DSon(25°C)}}$$

Fig. 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values



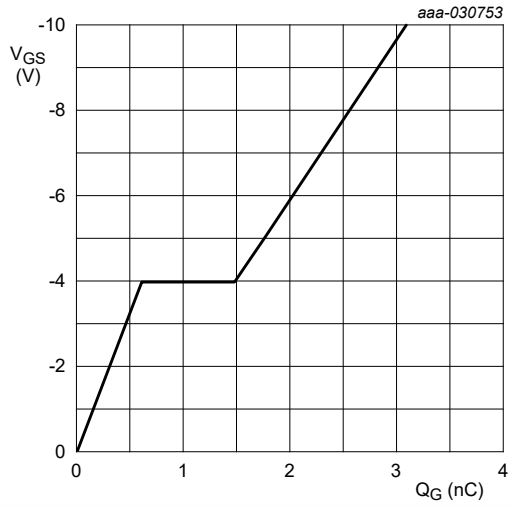
I_D = 250 µA; V_{DS} = V_{GS}

Fig. 12. Gate-source threshold voltage as a function of junction temperature



f = 1 MHz; V_{GS} = 0 V

Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



I_D = -0.6 A; V_{DS} = -50 V; T_j = 25 °C

Fig. 14. Gate-source voltage as a function of gate charge; typical values

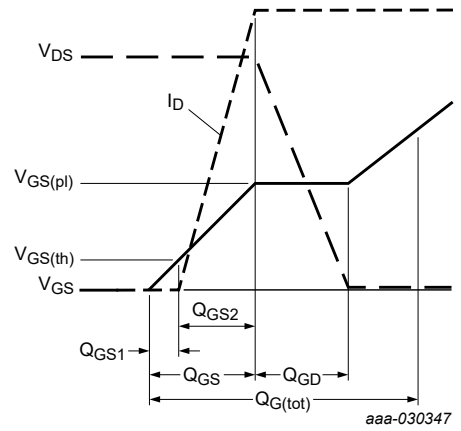
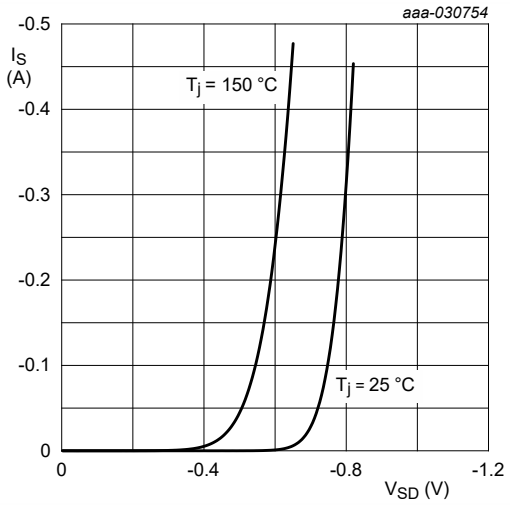


Fig. 15. Gate charge waveform definitions



V_{GS} = 0 V

Fig. 16. Source current as a function of source-drain voltage; typical values

11. Test information

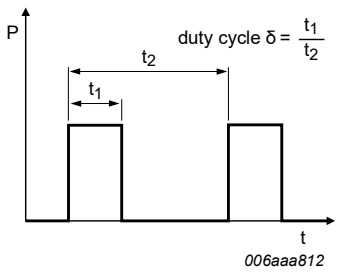
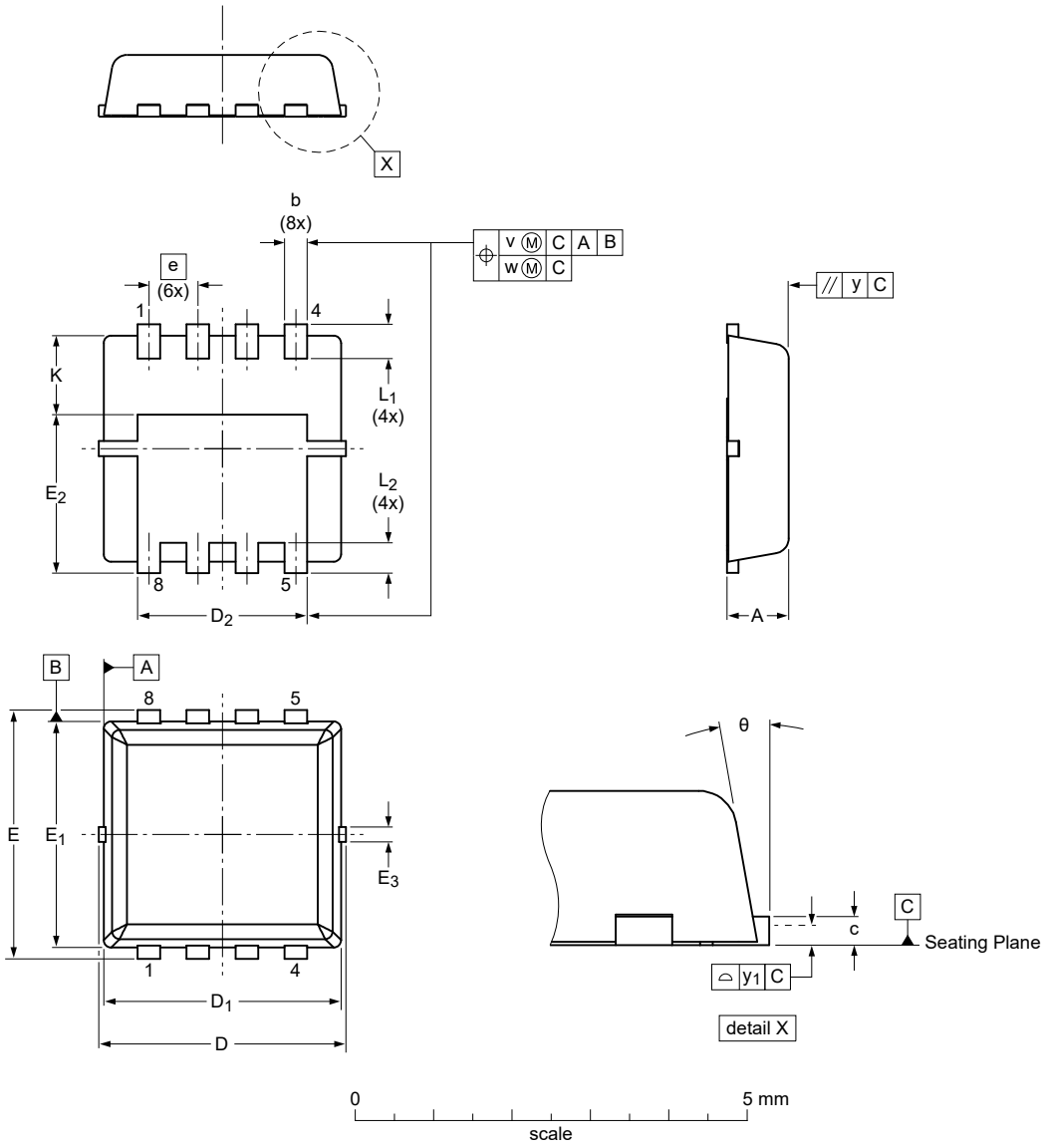


Fig. 17. Duty cycle definition

12. Package outline

MLPAK33: plastic thermal enhanced surface mounted package; mini leads; 8 terminals; pitch 0.65 mm; 3.3 x 3.3 x 0.8 mm body **SOT8002-2**



Dimensions (mm are the original dimensions)

Unit		A	b	c	D	D_1	D_2	e	E	E_1	E_2	E_3	K	L_1	L_2	θ	y	y_1	v	w
mm	max	0.90	0.35	0.18	3.40	3.20	2.35	0.65	3.35	3.10	2.20	0.25	0.6 (ref)	0.55	0.50	12°	0.05	0.05	0.1	0.05
	nom	0.80	0.30	0.15	3.30	3.15	2.25		3.30	3.00	2.10	0.20		0.45	0.40	10°				
	min	0.70	0.25	0.12	3.20	3.10	2.15		3.25	2.90	2.00	0.15		0.35	0.30	8°				

sot8002-2_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	EIAJ			
SOT8002-2						~~19-12-19~~ 20-01-08

Fig. 18. Package outline MLPAK33 (SOT8002-2)

13. Soldering

Footprint information for reflow soldering of MLPAK33 package **SOT8002-2**

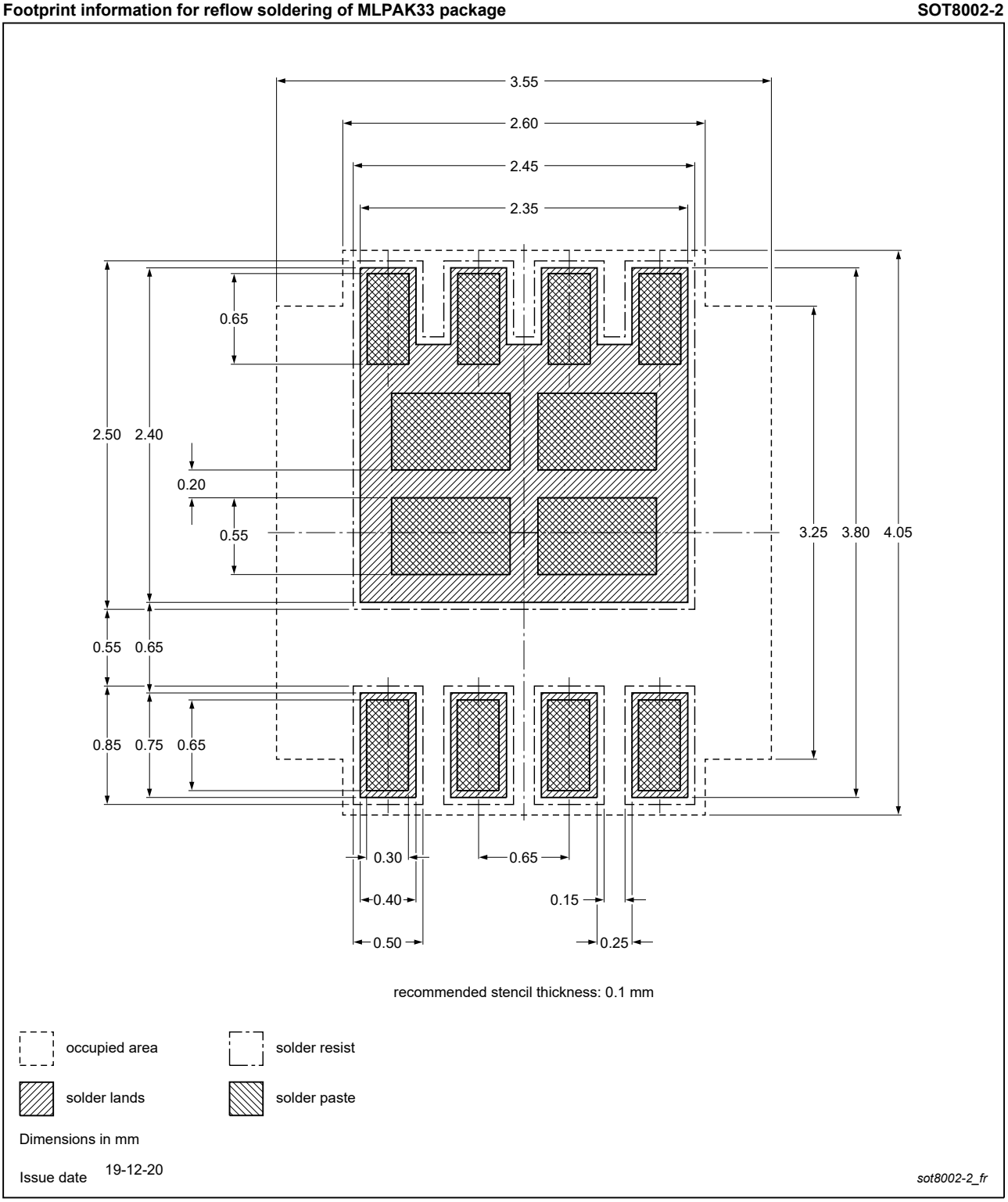


Fig. 19. Reflow soldering footprint for MLPAK33 (SOT8002-2)

14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PXP1500-100QS v.2	20211120	Product data sheet	-	PXP1500-100QS v.1
Modifications:	• Chapter "Limiting values": P_{tot} corrected, now matching the data in chapter "Thermal characteristics"			
PXP1500-100QS v.1	20200507	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.
[2] The term 'short data sheet' is explained in section "Definitions".
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